

Power Matters.™

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JAN2N1016D (#68502)

Overview

Electrical Rating	Symbol	Min	Typ	Max	Unit
DC Current Gain	HFE	10.00		35.00	
Drain Current (dc)	I _D			7.50	A
Turn Off Time (nS)	t _{off}			15000.00	ns

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector-Emitter Voltage (Base Open)	V _{CEO}			100.00	V
Junction Temperature (°C)	T _J			200.00	°C

This part can be found in the following product categories:

- Non-Radiation Hardened Devices > Transistors > BJT(BiPolar Junction Transistor) > NPN Transistor
- Discretes > Transistors > BJT(BiPolar Junction Transistor) > NPN Transistor

Related Links

- Technical support
- Sales Contacts
- Available Stock
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- RFQ/Samples